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APPLICATION NO.	FILING DATE	FIRST NAMED INVENTOR	ATTORNEY DOCKET NO.	ATTORNEY DOCKET NO. CONFIRMATION NO.	
10/772,029	02/03/2004	Michael Pelham	TRAN-P151 3885		
75	590 11/20/2006	EXAMINER			
WAGNER, MURABITO & HAO LLP Two North Market Street, Third Floor San Jose, CA 95113			LUU, CHUONG A		
			ART UNIT	PAPER NUMBER	
<b>Sun 1 500</b> 5, 51 1			2818		
			DATE MAILED: 11/20/2006		

Please find below and/or attached an Office communication concerning this application or proceeding.

Office Action Summary		Application	on No. Applicant(s)					
		10/772,02	9	PELHAM ET AL.				
		Examiner		Art Unit				
		Chuong A.		2818				
The MAILING DATE of this communication appears on the cover sheet with the correspondence address Period for Reply								
WHIC - Exte after - If NC - Failu Any	ORTENED STATUTORY PERIOD FOR CHEVER IS LONGER, FROM THE MAILInsions of time may be available under the provisions of 37 SIX (6) MONTHS from the mailing date of this communical period for reply is specified above, the maximum statutory re to reply within the set or extended period for reply will, be reply received by the Office later than three months after the patent term adjustment. See 37 CFR 1.704(b).	ING DATE OF TH CFR 1.136(a). In no eve tion. y period will apply and will by statute, cause the appli	IS COMMUNICATION int, however, may a reply be tim I expire SIX (6) MONTHS from cation to become ABANDONED	I. lely filed the mailing date of this co D (35 U.S.C. § 133).	, ,			
Status					•			
1)⊠ 2a)□ 3)□	Responsive to communication(s) filed on This action is <b>FINAL</b> . 2b) Since this application is in condition for a closed in accordance with the practice up	☐ This action is no allowance except t	for formal matters, pro		merits is			
Disposit	on of Claims							
5)□ 6)⊠ 7)⊠ 8)□ <b>Applicat</b> i	Claim(s) 1-5 and 8 is/are pending in the 4a) Of the above claim(s) is/are w Claim(s) is/are allowed.  Claim(s) 1-4 and 8 is/are rejected.  Claim(s) 5 is/are objected to.  Claim(s) are subject to restriction  on Papers  The specification is objected to by the Ex The drawing(s) filed on is/are: a)[ Applicant may not request that any objection Replacement drawing sheet(s) including the	and/or election recaminer.  accepted or b)[ to the drawing(s) be	equirement.  ☐ objected to by the Earth of the Part of the Earth of t	37 CFR 1.85(a).	R 1.121(d).			
11) The oath or declaration is objected to by the Examiner. Note the attached Office Action or form PTO-152.								
Priority ι	ınder 35 U.S.C. § 119							
<ul> <li>12) Acknowledgment is made of a claim for foreign priority under 35 U.S.C. § 119(a)-(d) or (f).</li> <li>a) All b) Some * c) None of:</li> <li>1. Certified copies of the priority documents have been received.</li> <li>2. Certified copies of the priority documents have been received in Application No</li> <li>3. Copies of the certified copies of the priority documents have been received in this National Stage application from the International Bureau (PCT Rule 17.2(a)).</li> <li>* See the attached detailed Office action for a list of the certified copies not received.</li> </ul>								
2)  Notic 3) Inforr	e of References Cited (PTO-892) e of Draftsperson's Patent Drawing Review (PTO-9 nation Disclosure Statement(s) (PTO-1449 or PTO/ r No(s)/Mail Date	48) 'SB/08)	4) Interview Summary ( Paper No(s)/Mail Da 5) Notice of Informal Pa 6) Other:	te	-152)			

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### **DETAILED ACTION**

# Response to Arguments

Applicant's arguments with respect to claims 1-5 and 8 have been considered but are most in view of the new ground(s) of rejection.

#### PRIOR ART REJECTIONS

## **Statutory Basis**

# Claim Rejections - 35 USC § 102

The following is a quotation of the appropriate paragraphs of 35 U.S.C. 102 that form the basis for the rejections under this section made in this Office action:

A person shall be entitled to a patent unless -

- (b) the invention was patented or described in a printed publication in this or a foreign country or in public use or on sale in this country, more than one year prior to the date of application for patent in the United States.
- (e) the invention was described in (1) an application for patent, published under section 122(b), by another filed in the United States before the invention by the applicant for patent or (2) a patent granted on an application for patent by another filed in the United States before the invention by the applicant for patent, except that an international application filed under the treaty defined in section 351(a) shall have the effects for purposes of this subsection of an application filed in the United States only if the international application designated the United States and was published under Article 21(2) of such treaty in the English language.

## The Rejections

Claims 1-5 and 8 are rejected under 35 U.S.C. 102(b) as being anticipated by Sakai (U.S. 4,907,058).

Sakai discloses a complementary semiconductor device with

(1) specifying a tile comprising a first layer wherein said first layer comprises a first layer element for a deep N-well pattern:

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arranging multiple instances of said tile to create a tile array covering a portion of said integrated circuit design;

merging said tiles to produce a deep N-well pattern (see Figure 2B);

- (2) wherein said tile further comprises a second layer, wherein said second layer comprises a second layer element (see Figure 2B);
- (3) wherein said first layer element is identical in shape to said second layer element (see Figure 2B);
- (4) wherein said first layer element is disposed rotated with respect to said second layer element (see Figure 2B);
- (8) further comprising flattening said first layer and said second layer (see Figure2B).

Claims 1-5 and 8 are rejected under 35 U.S.C. 102(b) as being anticipated by Masleid et al. (U.S. 7,049,699).

Masleid discloses a low RC structure with

(1) specifying a tile comprising a first layer wherein said first layer comprises a first layer element for a deep N-well pattern;

arranging multiple instances of said tile to create a tile array covering a portion of said integrated circuit design;

merging said tiles to produce a deep N-well pattern (see Figures 5A-5B);

(2) wherein said tile further comprises a second layer, wherein said second layer comprises a second layer element (see Figures 5A-5B);

(3) wherein said first layer element is identical in shape to said second layer element (see Figures 5A-5B);

- (4) wherein said first layer element is disposed rotated with respect to said second layer element (see Figures 5A-5B);
- (8) further comprising flattening said first layer and said second layer (see Figures 5A-5B).

# Allowable Subject Matter

Claim 5 is objected to as being dependent upon a rejected base claim, but would be allowable if rewritten in independent form including all of the limitations of the base claim and any intervening claims.

#### Conclusion

Any inquiry concerning this communication or earlier communications from the examiner should be directed to Chuong A. Luu whose telephone number is (571) 272-1902. The examiner can normally be reached on M-F (6:15-2:45).

If attempts to reach the examiner by telephone are unsuccessful, the examiner's supervisor, Matthew Smith can be reached on (571) 272-1907. The fax phone number for the organization where this application or proceeding is assigned is 571-273-8300.

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Chuong Anh Luu Patent Examiner November 01, 2006